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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

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Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	Brown-out Detect/Reset, POR, WDT
Number of I/O	13
Program Memory Size	896B (512 x 14)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	96 x 8
Voltage - Supply (Vcc/Vdd)	2.5V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	18-SOIC (0.295", 7.50mm Width)
Supplier Device Package	18-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c620at-04i-so

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

NOTES:

FIGURE 3-1: BLOCK DIAGRAM

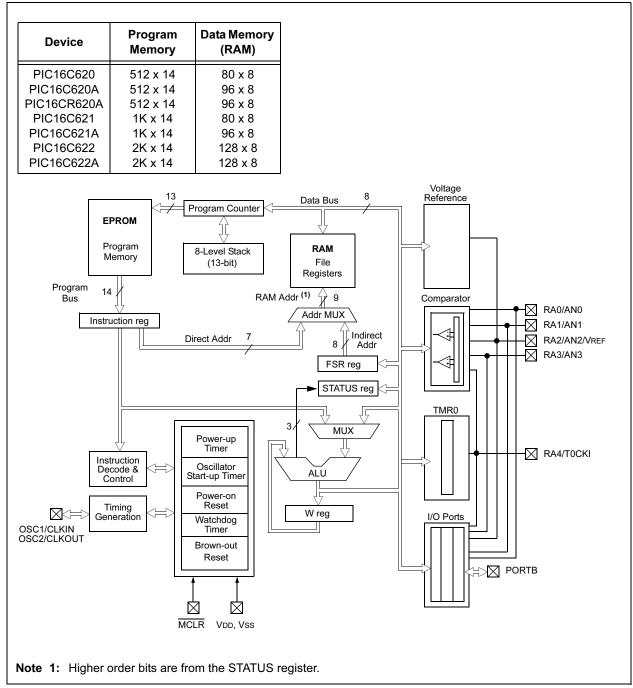


FIGURE 4-4: DATA MEMORY MAP FOR THE PIC16C620/621

File			File
Address	3		Address
00h	INDF ⁽¹⁾	INDF ⁽¹⁾	80h
01h	TMR0	OPTION	81h
02h	PCL	PCL	82h
03h	STATUS	STATUS	83h
04h	FSR	FSR	84h
05h	PORTA	TRISA	85h
06h	PORTB	TRISB	86h
07h			87h
08h			88h
09h			89h
0Ah	PCLATH	PCLATH	8Ah
0Bh	INTCON	INTCON	8Bh
0Ch	PIR1	PIE1	8Ch
0Dh			8Dh
0Eh		PCON	8Eh
0Fh			8Fh
10h			90h
11h			91h
12h			92h
13h			93h
14h			94h
15h			95h
16h			96h
17h			97h
18h			98h
19h			99h
1Ah			9Ah
1Bh			9Bh
1Ch			9Ch
1Dh			9Dh
1Eh			9Eh
1Fh	CMCON	VRCON	9Fh
20h		_	A0h
	General		
	Purpose Register		
6Fh	5		
70h			
7Fh			FFh
	Bank 0	Bank 1	
—		1 4	
Unimp	plemented data me	mory locations, r	ead as '0'.
Note 1:	Not a physical re	egister.	

FIGURE 4-5:

DATA MEMORY MAP FOR THE PIC16C622

	1116		
File Address	8		File Address
00h	INDF ⁽¹⁾	INDF ⁽¹⁾	80h
01h	TMR0	OPTION	81h
02h	PCL	PCL	82h
03h	STATUS	STATUS	83h
04h	FSR	FSR	84h
05h	PORTA	TRISA	85h
06h	PORTB	TRISB	86h
00h	TOILID	TRIOD	87h
07h 08h			88h
00h			89h
03h 0Ah	PCLATH	PCLATH	8Ah
0An 0Bh	INTCON	INTCON	8Bh
0Dh	PIR1	PIE1	8Ch
0Ch 0Dh	PIRI	PIEI	8Dh
		PCON	
0Eh 0Fh		PCON	8Eh
			8Fh
10h			90h
11h			91h
12h			92h
13h			93h
14h			94h
15h			95h
16h			96h
17h			97h
18h			98h
19h			99h
1Ah			9Ah
1Bh			9Bh
1Ch			9Ch
1Dh			9Dh
1Eh			9Eh
1Fh	CMCON	VRCON	9Fh
20h			A0h
	General Purpose	General Purpose	
	Register	Register	
	0	5	BFh
			C0h
7Fh			FFh
, , , , , ,	Bank 0	Bank 1	
Unim	plemented data me	mory locations, re	ad as '0'.
Note 1:	Not a physical re	aister	

4.4 Indirect Addressing, INDF and FSR Registers

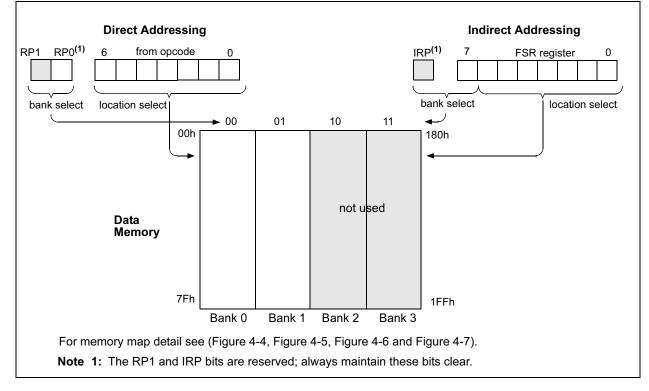
The INDF register is not a physical register. Addressing the INDF register will cause indirect addressing.

Indirect addressing is possible by using the INDF register. Any instruction using the INDF register actually accesses data pointed to by the File Select Register (FSR). Reading INDF itself indirectly will produce 00h. Writing to the INDF register indirectly results in a no-operation (although STATUS bits may be affected). An effective 9-bit address is obtained by concatenating the 8-bit FSR register and the IRP bit (STATUS<7>), as shown in Figure 4-9. However, IRP is not used in the PIC16C62X.

A simple program to clear RAM location 20h-7Fh using indirect addressing is shown in Example 4-1.

EXAN	IPLE 4-	1: INC	DIRECT ADDRESSING
	movlw	0x20	;initialize pointer
	movwf	FSR	;to RAM
NEXT	clrf	INDF	;clear INDF register
	incf	FSR	;inc pointer
	btfss	FSR,7	;all done?
	goto	NEXT	;no clear next
			;yes continue
CONTI	NUE:		

FIGURE 4-9: DIRECT/INDIRECT ADDRESSING PIC16C62X



Name	Bit #	Buffer Type	Function
RB0/INT	bit0	TTL/ST ⁽¹⁾	Input/output or external interrupt input. Internal software programmable weak pull-up.
RB1	bit1	TTL	Input/output pin. Internal software programmable weak pull-up.
RB2	bit2	TTL	Input/output pin. Internal software programmable weak pull-up.
RB3	bit3	TTL	Input/output pin. Internal software programmable weak pull-up.
RB4	bit4	TTL	Input/output pin (with interrupt-on-change). Internal software programmable weak pull-up.
RB5	bit5	TTL	Input/output pin (with interrupt-on-change). Internal software programmable weak pull-up.
RB6	bit6	TTL/ST ⁽²⁾	Input/output pin (with interrupt-on-change). Internal software programmable weak pull-up. Serial programming clock pin.
RB7	bit7	TTL/ST ⁽²⁾	Input/output pin (with interrupt-on-change). Internal software programmable weak pull-up. Serial programming data pin.

TABLE 5-3: PORTB FUNCTIONS

Legend: ST = Schmitt Trigger, TTL = TTL input

Note 1: This buffer is a Schmitt Trigger input when configured as the external interrupt.

2: This buffer is a Schmitt Trigger input when used in Serial Programming mode.

TABLE 5-4: SUMMARY OF REGISTERS ASSOCIATED WITH PORTB

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on POR	Value on All Other RESETS
06h	PORTB	RB7	RB6	RB5	RB4	RB3	RB2	RB1	RB0	XXXX XXXX	uuuu uuuu
86h	TRISB	TRISB7	TRISB6	TRISB5	TRISB4	TRISB3	TRISB2	TRISB1	TRISB0	1111 1111	1111 1111
81h	OPTION	RBPU	INTEDG	TOCS	T0SE	PSA	PS2	PS1	PS0	1111 1111	1111 1111

Legend: u = unchanged, x = unknown

Note 1: Shaded bits are not used by PORTB.

NOTES:

TABLE 9-4: INITIALIZATION CONDITION FOR SPECIAL REGISTERS

Condition	Program Counter	STATUS Register	PCON Register
Power-on Reset	000h	0001 1xxx	0x
MCLR Reset during normal operation	000h	000u uuuu	uu
MCLR Reset during SLEEP	000h	0001 0uuu	uu
WDT Reset	000h	0000 uuuu	uu
WDT Wake-up	PC + 1	uuu0 0uuu	uu
Brown-out Reset	000h	000x xuuu	u0
Interrupt Wake-up from SLEEP	PC + 1 ⁽¹⁾	uuu1 0uuu	uu

Legend: u = unchanged, x = unknown, - = unimplemented bit, reads as '0'.

Note 1: When the wake-up is due to an interrupt and global enable bit, GIE is set, the PC is loaded with the interrupt vector (0004h) after execution of PC+1.

Register	Address	Power-on Reset	 MCLR Reset during normal operation MCLR Reset during SLEEP WDT Reset Brown-out Reset ⁽¹⁾ 	 Wake-up from SLEEP through interrupt Wake-up from SLEEP through WDT time-out
W	_	xxxx xxxx	<u>uuuu</u> uuuu	<u></u>
INDF	00h		_	_
TMR0	01h	xxxx xxxx	սսսս սսսս	นนนน นนนน
PCL	02h	0000 0000	0000 0000	PC + 1 ⁽³⁾
STATUS	03h	0001 1xxx	000q quuu ⁽⁴⁾	uuuq quuu ⁽⁴⁾
FSR	04h	xxxx xxxx	սսսս սսսս	<u>uuuu</u> uuuu
PORTA	05h	x xxxx	u uuuu	u uuuu
PORTB	06h	xxxx xxxx	uuuu uuuu	uuuu uuuu
CMCON	1Fh	00 0000	00 0000	uu uuuu
PCLATH	0Ah	0 0000	0 0000	u uuuu
INTCON	0Bh	0000 000x	0000 000u	uuuu uqqq ⁽²⁾
PIR1	0Ch	-0	-0	-q (2,5)
OPTION	81h	1111 1111	1111 1111	uuuu uuuu
TRISA	85h	1 1111	1 1111	u uuuu
TRISB	86h	1111 1111	1111 1111	uuuu uuuu
PIE1	8Ch	-0	-0	-u
PCON	8Eh	0x	uq ^(1,6)	uu
VRCON	9Fh	000- 0000	000- 0000	uuu- uuuu

TABLE 9-5: INITIALIZATION CONDITION FOR REGISTERS

 $\label{eq:legend: u = unchanged, x = unknown, - = unimplemented bit, reads as `0', q = value depends on condition.$

Note 1: If VDD goes too low, Power-on Reset will be activated and registers will be affected differently.

2: One or more bits in INTCON, PIR1 and/or PIR2 will be affected (to cause wake-up).

3: When the wake-up is due to an interrupt and the GIE bit is set, the PC is loaded with the interrupt vector (0004h).

4: See Table 9-4 for RESET value for specific condition.

5: If wake-up was due to comparator input changing, then bit 6 = 1. All other interrupts generating a wake-up will cause bit 6 = u.

6: If RESET was due to brown-out, then bit 0 = 0. All other RESETS will cause bit 0 = u.

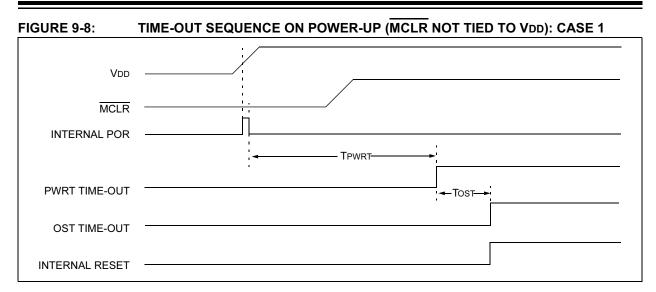


FIGURE 9-9: TIME-OUT SEQUENCE ON POWER-UP (MCLR NOT TIED TO VDD): CASE 2

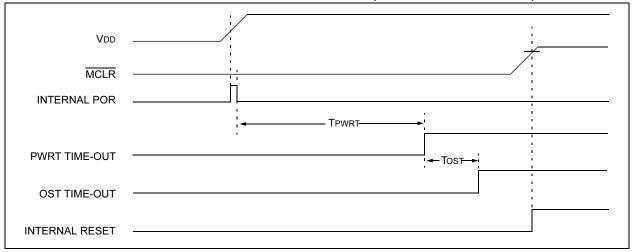


FIGURE 9-10: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD)

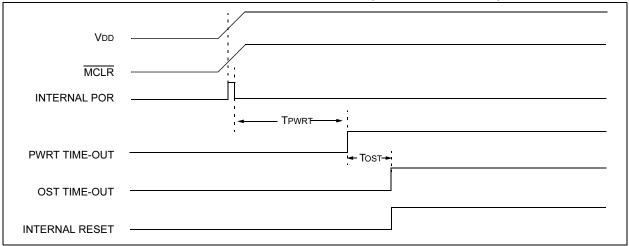
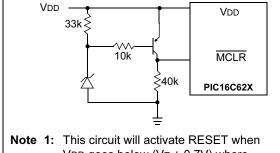


FIGURE 9-11: EXTERNAL POWER-ON RESET CIRCUIT (FOR SLOW VDD POWER-UP) Vdd Vdd D R R1 MCLR PIC16C62X С Note 1: External Power-on Reset circuit is required only if VDD power-up slope is too slow. The diode D helps discharge the capacitor quickly when VDD powers down. **2:** < 40 k Ω is recommended to make sure that voltage drop across R does not violate the device's electrical specification. **3:** R1 = 100Ω to 1 k Ω will limit any current flowing into MCLR from external capacitor C in the event of MCLR/VPP pin

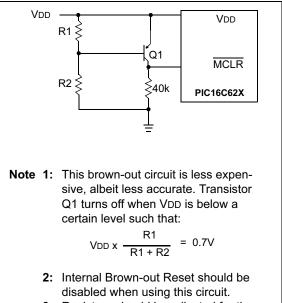
breakdown due to Electrostatic Discharge (ESD) or Electrical Overstress (EOS).

FIGURE 9-12: EXTERNAL BROWN-OUT PROTECTION CIRCUIT 1



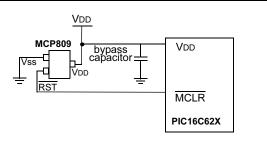
- Note 1: This circuit will activate RESET when VDD goes below (Vz + 0.7V) where Vz = Zener voltage.
 - **2:** Internal Brown-out Reset circuitry should be disabled when using this circuit.

FIGURE 9-13: EXTERNAL BROWN-OUT PROTECTION CIRCUIT 2



3: Resistors should be adjusted for the characteristics of the transistor.

FIGURE 9-14: EXTERNAL BROWN-OUT PROTECTION CIRCUIT 3



This brown-out protection circuit employs Microchip Technology's MCP809 microcontroller supervisor. The MCP8XX and MCP1XX families of supervisors provide push-pull and open collector outputs with both high and low active RESET pins. There are 7 different trip point selections to accommodate 5V and 3V systems.

TABLE 10-2: PIC16C62X INSTRUCTION SET

Mnemonic, Operands		Description	Cycles		14-Bit	Opcode	Status Affected	Notes	
				MSb				LSb	
BYTE-OR	IENTED I	FILE REGISTER OPERATIONS							
ADDWF	f, d	Add W and f	1	00	0111	dfff	ffff	C,DC,Z	1,2
ANDWF	f, d	AND W with f	1	00	0101	dfff	ffff	Z	1,2
CLRF	f	Clear f	1	00	0001	lfff	ffff	Z	2
CLRW	-	Clear W	1	00	0001	0000	0011	Z	
COMF	f, d	Complement f	1	00	1001	dfff	ffff	Z	1,2
DECF	f, d	Decrement f	1	00	0011	dfff	ffff	Z	1,2
DECFSZ	f, d	Decrement f, Skip if 0	1(2)	00	1011	dfff	ffff		1,2,3
INCF	f, d	Increment f	1	00	1010	dfff	ffff	Z	1,2
INCFSZ	f, d	Increment f, Skip if 0	1(2)	00	1111	dfff	ffff		1,2,3
IORWF	f, d	Inclusive OR W with f	1	00	0100	dfff	ffff	Z	1,2
MOVF	f, d	Move f	1	00	1000	dfff	ffff	Z	1,2
MOVWF	f	Move W to f	1	00	0000	lfff	ffff		
NOP	-	No Operation	1	00	0000	0xx0	0000		
RLF	f, d	Rotate Left f through Carry	1	00	1101	dfff	ffff	С	1,2
RRF	f, d	Rotate Right f through Carry	1	00	1100	dfff	ffff	С	1,2
SUBWF	f, d	Subtract W from f	1	00	0010	dfff	ffff	C,DC,Z	1,2
SWAPF	f, d	Swap nibbles in f	1	00	1110	dfff	ffff		1,2
XORWF	f, d	Exclusive OR W with f	1	00	0110	dfff	ffff	Z	1,2
BIT-ORIEN	NTED FIL	E REGISTER OPERATIONS						•	
BCF	f, b	Bit Clear f	1	01	00bb	bfff	ffff		1,2
BSF	f, b	Bit Set f	1	01	01bb	bfff	ffff		1,2
BTFSC	f, b	Bit Test f, Skip if Clear	1 (2)	01	10bb	bfff	ffff		3
BTFSS	f, b	Bit Test f, Skip if Set	1 (2)	01	11bb	bfff	ffff		3
LITERAL	AND CO	NTROL OPERATIONS							
ADDLW	k	Add literal and W	1	11	111x	kkkk	kkkk	C,DC,Z	
ANDLW	k	AND literal with W	1	11	1001	kkkk	kkkk	Z	
CALL	k	Call subroutine	2	10	0kkk	kkkk	kkkk		
CLRWDT	-	Clear Watchdog Timer	1	00	0000	0110	0100	TO,PD	
GOTO	k	Go to address	2	10	1kkk	kkkk	kkkk		
IORLW	k	Inclusive OR literal with W	1	11	1000	kkkk	kkkk	Z	
MOVLW	k	Move literal to W	1	11	00xx	kkkk	kkkk		
RETFIE	-	Return from interrupt	2	00	0000	0000	1001		
RETLW	k	Return with literal in W	2	11	01xx	kkkk	kkkk		
RETURN	-	Return from Subroutine	2	00	0000	0000	1000		
SLEEP	-	Go into Standby mode	1	00	0000	0110	0011	TO,PD	
SUBLW	k	Subtract W from literal	1	11	110x	kkkk	kkkk	C,DC,Z	
XORLW	k	Exclusive OR literal with W	1	11	1010	kkkk	kkkk	Z	

Note 1: When an I/O register is modified as a function of itself (e.g., MOVF PORTB, 1), the value used will be that value present on the pins themselves. For example, if the data latch is '1' for a pin configured as input and is driven low by an external device, the data will be written back with a '0'.

2: If this instruction is executed on the TMR0 register (and, where applicable, d = 1), the prescaler will be cleared if assigned to the Timer0 Module.

3: If Program Counter (PC) is modified or a conditional test is true, the instruction requires two cycles. The second cycle is executed as a NOP.

NOTES:

11.9 MPLAB ICE 2000 High Performance Universal In-Circuit Emulator

The MPLAB ICE 2000 universal in-circuit emulator is intended to provide the product development engineer with a complete microcontroller design tool set for PICmicro microcontrollers. Software control of the MPLAB ICE 2000 in-circuit emulator is advanced by the MPLAB Integrated Development Environment, which allows editing, building, downloading and source debugging from a single environment.

The MPLAB ICE 2000 is a full-featured emulator system with enhanced trace, trigger and data monitoring features. Interchangeable processor modules allow the system to be easily reconfigured for emulation of different processors. The universal architecture of the MPLAB ICE in-circuit emulator allows expansion to support new PICmicro microcontrollers.

The MPLAB ICE 2000 in-circuit emulator system has been designed as a real-time emulation system with advanced features that are typically found on more expensive development tools. The PC platform and Microsoft[®] Windows 32-bit operating system were chosen to best make these features available in a simple, unified application.

11.10 MPLAB ICE 4000 High Performance Universal In-Circuit Emulator

The MPLAB ICE 4000 universal in-circuit emulator is intended to provide the product development engineer with a complete microcontroller design tool set for highend PICmicro microcontrollers. Software control of the MPLAB ICE in-circuit emulator is provided by the MPLAB Integrated Development Environment, which allows editing, building, downloading and source debugging from a single environment.

The MPLAB ICD 4000 is a premium emulator system, providing the features of MPLAB ICE 2000, but with increased emulation memory and high speed performance for dsPIC30F and PIC18XXXX devices. Its advanced emulator features include complex triggering and timing, up to 2 Mb of emulation memory, and the ability to view variables in real-time.

The MPLAB ICE 4000 in-circuit emulator system has been designed as a real-time emulation system with advanced features that are typically found on more expensive development tools. The PC platform and Microsoft Windows 32-bit operating system were chosen to best make these features available in a simple, unified application.

11.11 MPLAB ICD 2 In-Circuit Debugger

Microchip's In-Circuit Debugger, MPLAB ICD 2, is a powerful, low cost, run-time development tool, connecting to the host PC via an RS-232 or high speed USB interface. This tool is based on the FLASH PICmicro MCUs and can be used to develop for these and other PICmicro microcontrollers. The MPLAB ICD 2 utilizes the in-circuit debugging capability built into the FLASH devices. This feature, along with Microchip's In-Circuit Serial Programming[™] (ICSP[™]) protocol, offers cost effective in-circuit FLASH debugging from the graphical user interface of the MPLAB Integrated Development Environment. This enables a designer to develop and debug source code by setting breakpoints, single-stepping and watching variables, CPU status and peripheral registers. Running at full speed enables testing hardware and applications in real-time. MPLAB ICD 2 also serves as a development programmer for selected PICmicro devices.

11.12 PRO MATE II Universal Device Programmer

The PRO MATE II is a universal, CE compliant device programmer with programmable voltage verification at VDDMIN and VDDMAX for maximum reliability. It features an LCD display for instructions and error messages and a modular detachable socket assembly to support various package types. In Stand-Alone mode, the PRO MATE II device programmer can read, verify, and program PICmicro devices without a PC connection. It can also set code protection in this mode.

11.13 PICSTART Plus Development Programmer

The PICSTART Plus development programmer is an easy-to-use, low cost, prototype programmer. It connects to the PC via a COM (RS-232) port. MPLAB Integrated Development Environment software makes using the programmer simple and efficient. The PICSTART Plus development programmer supports most PICmicro devices up to 40 pins. Larger pin count devices, such as the PIC16C92X and PIC17C76X, may be supported with an adapter socket. The PICSTART Plus development programmer is CE compliant.

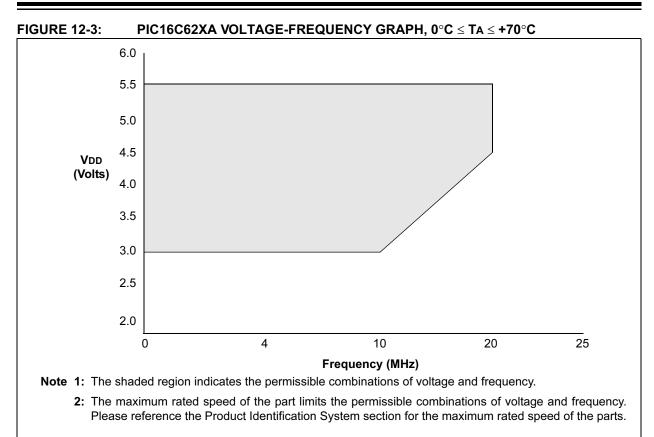
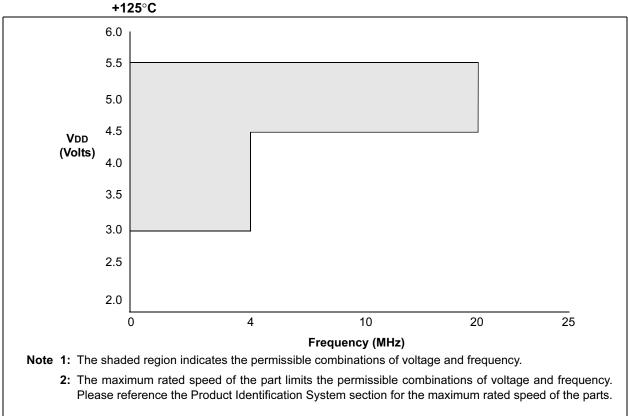
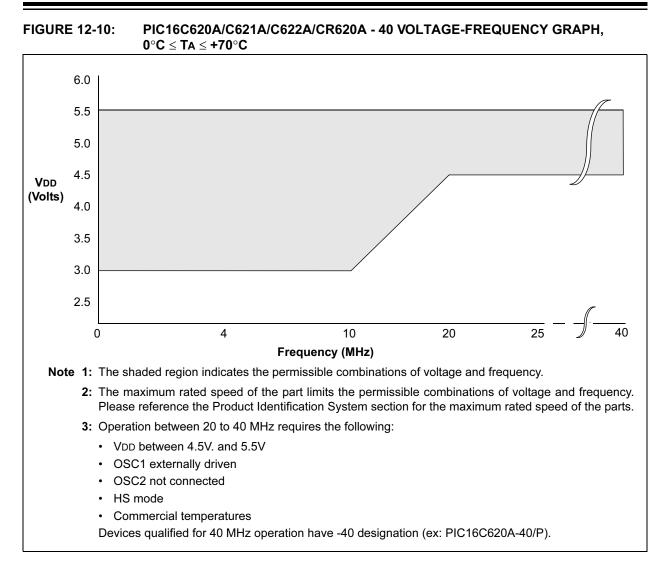


FIGURE 12-4: PIC16C62XA VOLTAGE-FREQUENCY GRAPH, $-40^{\circ}C \le Ta \le 0^{\circ}C$, $+70^{\circ}C \le Ta \le +125^{\circ}C$





12.2 DC Characteristics: PIC16C62XA-04 (Commercial, Industrial, Extended) PIC16C62XA-20 (Commercial, Industrial, Extended) PIC16LC62XA-04 (Commercial, Industrial, Extended) (CONT.)

PIC16L0	$-40^{\circ}C \leq TA \leq +12$ $Standard Operating Conditions (unless)$ $Operating temperature -40^{\circ}C \leq TA \leq +8$ $0^{\circ}C \leq TA \leq +70$ $-40^{\circ}C \leq TA \leq +1$						$\begin{array}{llllllllllllllllllllllllllllllllllll$
Param. No.	Sym	Characteristic	Min	Тур†	Мах	Units	Conditions
D010	IDD	Supply Current ^(2, 4)	_	1.2 0.4 1.0	2.0 1.2 2.0	mA mA mA	Fosc = 4 MHz, VDD = 5.5V, WDT disabled, XT mode, (Note 4)* Fosc = 4 MHz, VDD = 3.0V, WDT disabled, XT mode, (Note 4)* Fosc = 10 MHz, VDD = 3.0V, WDT dis-
			_	4.0	6.0 7.0	mA mA	abled, HS mode, (Note 6) Fosc = 20 MHz, VDD = 4.5V, WDT dis- abled, HS mode Fosc = 20 MHz, VDD = 5.5V, WDT dis-
			_	35	70	μA	abled*, HS mode Fosc = 32 kHz, VDD = 3.0V, WDT dis- abled, LP mode
D010	IDD	Supply Current ⁽²⁾	_	1.2 — 35	2.0 1.1 70	mA mA μA	Fosc = 4 MHz, VDD = 5.5V, WDT disabled, XT mode, (Note 4)* Fosc = 4 MHz, VDD = 2.5V, WDT disabled, XT mode, (Note 4) Fosc = 32 kHz, VDD = 2.5V, WDT dis-
D020	IPD	Power-down Current ⁽³⁾			2.2 5.0 9.0 15	μΑ μΑ μΑ μΑ	VDD = 3.0V VDD = 4.5V* VDD = 5.5V VDD = 5.5V Extended Temp.
D020	IPD	Power-down Current ⁽³⁾		 	2.0 2.2 9.0 15	μΑ μΑ μΑ μΑ	VDD = 2.5V VDD = 3.0V* VDD = 5.5V VDD = 5.5V Extended Temp.

These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: This is the limit to which VDD can be lowered without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as I/O pin loading and switching rate, oscillator type, internal code execution pattern, and temperature also have an impact on the current consumption.

The test conditions for all IDD measurements in Active Operation mode are:

OSC1 = external square wave, from rail to rail; all I/O pins tri-stated, pulled to VDD,

MCLR = VDD; WDT enabled/disabled as specified.

3: The power-down current in SLEEP mode does not depend on the oscillator type. Power-down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VDD or Vss.

4: For RC osc configuration, current through REXT is not included. The current through the resistor can be estimated by the formula: Ir = VDD/2REXT (mA) with REXT in kΩ.

5: The ∆ current is the additional current consumed when this peripheral is enabled. This current should be added to the base IDD or IPD measurement.

6: Commercial temperature range only.

12.2 DC Characteristics: PIC16C62XA-04 (Commercial, Industrial, Extended) PIC16C62XA-20 (Commercial, Industrial, Extended) PIC16LC62XA-04 (Commercial, Industrial, Extended (CONT.)

PIC16C62XA				ating te	mpera	ature -4 -4	ditions (unless otherwise stated) $40^{\circ}C \leq TA \leq +85^{\circ}C$ for industrial and $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial and $40^{\circ}C \leq TA \leq +125^{\circ}C$ for extended		
PIC16LC62XA				$\begin{array}{llllllllllllllllllllllllllllllllllll$					
Param. No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions		
D022	ΔIWDT	WDT Current ⁽⁵⁾	—	6.0	10 12	μA μA	VDD = 4.0V (125°C)		
D022A D023	Δ IBOR Δ ICOMP	Brown-out Reset Current ⁽⁵⁾ Comparator Current for each Comparator ⁽⁵⁾	_	75 30	125 60	μA μA	BOD enabled, VDD = 5.0V VDD = 4.0V		
D023A	$\Delta I V REF$	VREF Current ⁽⁵⁾	—	80	135	μA	VDD = 4.0V		
D022 D022A D023	ΔIWDT ΔIBOR ΔICOMP	WDT Current ⁽⁵⁾ Brown-out Reset Current ⁽⁵⁾ Comparator Current for each Comparator ⁽⁵⁾		6.0 75 30	10 12 125 60	μΑ μΑ μΑ	VDD=4.0V (125°C) BOD enabled, VDD = 5.0V VDD = 4.0V		
D023A	Δ IVREF	VREF Current ⁽⁵⁾	_	80	135	μA	VDD = 4.0V		
1A	Fosc	LP Oscillator Operating Frequency RC Oscillator Operating Frequency XT Oscillator Operating Frequency HS Oscillator Operating Frequency	0 0 0 0		200 4 4 20	kHz MHz MHz MHz	All temperatures All temperatures All temperatures All temperatures		
1A	Fosc	LP Oscillator Operating Frequency RC Oscillator Operating Frequency XT Oscillator Operating Frequency HS Oscillator Operating Frequency	0 0 0 0		200 4 4 20	kHz MHz MHz MHz	All temperatures All temperatures All temperatures All temperatures		

These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: This is the limit to which VDD can be lowered without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as I/O pin loading and switching rate, oscillator type, internal code execution pattern, and temperature also have an impact on the current consumption.

The test conditions for all IDD measurements in Active Operation mode are:

OSC1 = external square wave, from rail to rail; all I/O pins tri-stated, pulled to VDD,

 $\overline{\text{MCLR}}$ = VDD; WDT enabled/disabled as specified.

3: The power-down current in SLEEP mode does not depend on the oscillator type. Power-down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VDD or VSS.

4: For RC osc configuration, current through REXT is not included. The current through the resistor can be estimated by the formula: Ir = VDD/2REXT (mA) with REXT in kΩ.

5: The Δ current is the additional current consumed when this peripheral is enabled. This current should be added to the base IDD or IPD measurement.

6: Commercial temperature range only.

Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions	
10*	TosH2ckL	OSC1↑ to CLKOUT↓ ⁽¹⁾		75 —	200 400	ns ns	PIC16C62X(A) PIC16LC62X(A) PIC16CR62XA PIC16LCR62XA	
11*	TosH2ck H	OSC1↑ to CLKOUT↑ ⁽¹⁾		75 —	200 400	ns ns	PIC16C62X(A) PIC16LC62X(A) PIC16CR62XA PIC16LCR62XA	
12*	TckR	CLKOUT rise time ⁽¹⁾		35 —	100 200	ns ns	PIC16C62X(A) PIC16LC62X(A) PIC16CR62XA PIC16LCR62XA	
13*	TckF	CLKOUT fall time ⁽¹⁾		35 —	100 200	ns ns	PIC16C62X(A) PIC16LC62X(A) PIC16CR62XA PIC16LCR62XA	
14*	TckL2ioV	CLKOUT ↓ to Port out valid ⁽¹⁾	_	—	20	ns		
15*	TioV2ckH	Port in valid before CLKOUT ^{↑(1)}	Tosc +200 ns Tosc +400 ns	—	_	ns ns	PIC16C62X(A) PIC16LC62X(A) PIC16CR62XA PIC16LCR62XA	
16*	TckH2iol	Port in hold after CLKOUT ↑ ⁽¹⁾	0	—		ns		
17*	TosH2ioV	OSC1↑ (Q1 cycle) to Port out valid		50	150 300	ns ns	PIC16C62X(A) PIC16LC62X(A) PIC16CR62XA PIC16LCR62XA	
18*	TosH2iol	OSC1↑ (Q2 cycle) to Port input invalid (I/O in hold time)	100 200	_	_	ns ns	PIC16C62X(A) PIC16LC62X(A) PIC16CR62XA PIC16LCR62XA	
19*	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	0	—	_	ns		
20*	TioR	Port output rise time	_	10 —	40 80	ns ns	PIC16C62X(A) PIC16LC62X(A) PIC16CR62XA PIC16LCR62XA	
21*	TioF	Port output fall time	_	10 —	40 80	ns ns	PIC16C62X(A) PIC16LC62X(A) PIC16CR62XA PIC16LCR62XA	
22*	Tinp	RB0/INT pin high or low time	25 40	_	_	ns ns	PIC16C62X(A) PIC16LC62X(A) PIC16CR62XA PIC16LCR62XA	
23	Trbp	RB<7:4> change interrupt high or low time	Тсү			ns		

TABLE 12-4: CLKOUT AND I/O TIMING REQUIREMENTS

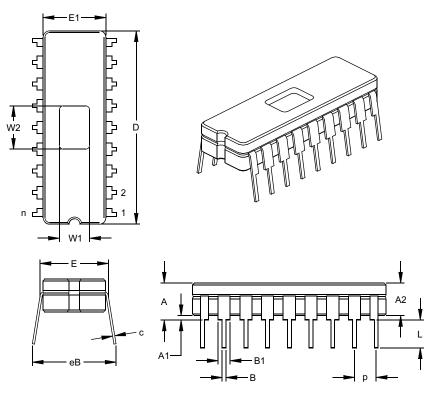
* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

14.0 PACKAGING INFORMATION

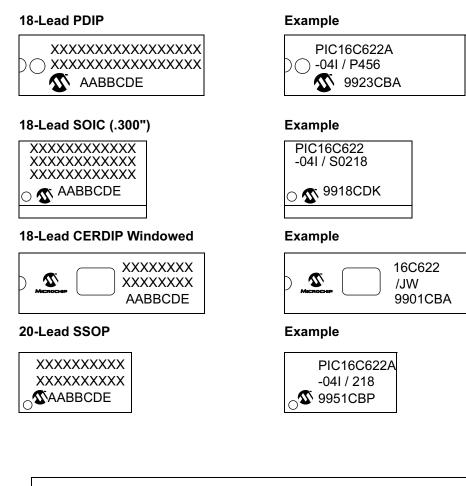
18-Lead Ceramic Dual In-line with Window (JW) – 300 mil (CERDIP)



	Units	Inits INCHES*			MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		18			18		
Pitch	р		.100			2.54		
Top to Seating Plane	Α	.170	.183	.195	4.32	4.64	4.95	
Ceramic Package Height	A2	.155	.160	.165	3.94	4.06	4.19	
Standoff	A1	.015	.023	.030	0.38	0.57	0.76	
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26	
Ceramic Pkg. Width	E1	.285	.290	.295	7.24	7.37	7.49	
Overall Length	D	.880	.900	.920	22.35	22.86	23.37	
Tip to Seating Plane	L	.125	.138	.150	3.18	3.49	3.81	
Lead Thickness	С	.008	.010	.012	0.20	0.25	0.30	
Upper Lead Width	B1	.050	.055	.060	1.27	1.40	1.52	
Lower Lead Width	В	.016	.019	.021	0.41	0.47	0.53	
Overall Row Spacing §	eB	.345	.385	.425	8.76	9.78	10.80	
Window Width	W1	.130	.140	.150	3.30	3.56	3.81	
Window Length	W2	.190	.200	.210	4.83	5.08	5.33	

* Controlling Parameter
 § Significant Characteristic
 JEDEC Equivalent: MO-036
 Drawing No. C04-010

14.1 Package Marking Information



Legend	d: XXX Y YY WW NNN	Customer specific information* Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code				
Note:	In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line thus limiting the number of available characters for customer specific information.					

* Standard PICmicro device marking consists of Microchip part number, year code, week code, and traceability code. For PICmicro device marking beyond this, certain price adders apply. Please check with your Microchip Sales Office. For QTP devices, any special marking adders are included in QTP price.



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